NSN 5961-01-522-3915

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View Online at https://aerobasegroup.com/nsn/5961-01-522-3915 **Inclosure Material:** Metal **Overall Length:** Between 0.790 inches and 0.800 inches **Overall Height:** Between 0.249 inches and 0.260 inches **Overall Width:** 0.540 inches **End Application:** Circuit card assembly; fighter aircraft-first (f18 e/f) **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Criticality Code Justification:** Agav **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 35.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector megawatts **Product Name:** Inavy: resistor, fixed, film; dwg: semiconductor, transistor, igbt, n-channel, silicon **Special Features:** High current n-channel, insulated gate bipolar transistor with added mil-prf-19500 quality assurance testing **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.